	1 ime: - 3 nrs. Warks: - 3	50
N.B.		
_	l is compulsory.	
	swer any <b>three</b> out of the remaining five questions.	
_	gures to the right indicate marks.	
4. An	swer to the questions should be grouped and written together.	
Ο1	Solve any four out of five	5
Q1. a.	What is the Over Drive Voltage and its Significance?	3
a.	What is the Over Brive Voltage and its Significance.	
b.	Explain DAC Specifications.	5
c.	Compare common source, Common gate and common Drain Amplifier in brief.	5
d.	Draw a simple current mirror circuit with the	5
	power supplies V+ = +5V, V = 0V, $I_{REF}$ = 0.30mA , $I_{O}$ = 0.10mA Kn ' = 40 uA/V Vth = 1V $\lambda$ =0	
	Design the MOSFETs	
e.	Explain various issues associated with Mixed Signal Circuit Layout.	
2. a.	Explain the difference and common mode of MOSFET differential Amplifiers	10
b.	For a NMOS Amplifier with driver $(M1)$ with Vin as the input voltage and PMOS as a load $(M2)$ with Vb as the input gate Voltage to the PMOS. The $V_{DD}=1.8V.$ $\lambda_1{=}0.1~V^{-1}$ , $\lambda_2{=}0.15~V^{-1}$ , $~u_nCox=200uA/V^2$ , $ Vth =0.4V$ The Amplifier should provide gain of $10$ with bias current of $0.5mA.$ Compute $(W/L)$ of $M1.$	10
Q3.	Find out the range of the differential input voltage for a MOSFET Differential	10
Q3.	Amplifier Amplifier	10
36		
b.	Derive the Voltage Gain for CS Stage with Diode Connected Load.	10
Q4.	Design a two stage Op-Amp for the following specifications	20
N. A.	Design a two stage Op-Amp with a phase margin of 60 degree and channel Length =1um	
	Av > 3500v/v, $Vdd = 2.5v$ , $Vss=-2.5v$ , $Gain Bandwidth = 6MHz$	
	Cload= $10pf$ , SR. $10 \text{ V/us}$ , Vout range = $+2 \text{ to } -2 \text{ v}$ ,	
	ICMR = $-1.125$ V to $+2$ V , Power Dissipation $< 2$ mw	
	$\varepsilon_0 = 8.854 \times 10^{-14} \text{F/cm}$	
	$\varepsilon_{si} = 11.7 \ \varepsilon_0 \ \text{F/cm}$	
	$\varepsilon_{\text{px}} = 3.9 \ \varepsilon_0 \ \text{F/cm}$	
	Threshold Voltage (NMOS) = 0.7V	
	Threshold Voltage (PMOS) = -0.7V  Channel length modulation index (NMOS) = 0.04 V <sup>-1</sup>	
	Channel length modulation index (NMOS) = $0.04 \text{ V}^{-1}$ Channel length modulation index (PMOS) = $0.05 \text{ V}^{-1}$	
	Chaimer length modulation muck (1 WOS) = 0.03 V	

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Q5. a.	Explain CASCODE Amplifier in general with the help of AC equivalent circuit.  Also draw the CASCODE Amplifier with CASCODE Load and Explain its Voltage
	gain and output Resistance.
b.	For a common Source Amplifier, explain the relation between the transconductance 10
	v/s input voltage.
Q6.	Write short notes on
a.	Successive Approximation method ADC 5
b.	Noise in MOSFETs. 5
c.	CMOS band gap reference generator. 5
d.	Triple CASCODE circuit 5

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